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## **IN THE SPECIFICATION**

After the title and before paragraph [0009], insert

FIELD OF THE INVENTION

Page 1, [0001] revise as follows:

I. The invention relates to a magnet configuration according to the preamble of patent claim 1.

Page 1, after paragraph [0001] insert

BACKGROUND OF THE INVENTION

Page 1, paragraph [0001] revise as follows:

In a sputter installation a plasma is generated in a vacuum in vacuo in a sputter chamber. Positive ions of the plasma are attracted by the negative potential of a cathode, which is provided with a so-called target. The positive ions impinge on this target and knock out small particles, which can become deposited on a substrate. Knocking out these particles is referred to as "sputtering". The plasma is comprised of gases which, in the case of non-reactive sputtering, can be inert gases, for example argon. In reactive sputtering, for example, oxygen is utilized alone or together with an inert gas.

Page 3, before paragraph [0008], insert

OBJECT AND SUMMARY OF THE INVENTION

Page 3, paragraph [0009], This objective is attained according to the present invention through the characteristics of patent claims 1 or 2.

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Page 3, paragraph [0011]

Embodiment examples of the invention are depicted in the drawing and will be described in further detail in the following. In the drawing depict:

Page 3, after paragraph [0011] insert

BRIEF DESCRIPTION OF THE DRAWINGS

Page 4, after paragraph [0018], insert

DETAILED DESCRIPTION

Page 10, before claim 1, delete

Patents Claims and insert It is claimed: